# VS-VSKDU162/12PbF

**Vishay Semiconductors** 



HEXFRED<sup>®</sup> Ultrafast Diodes, 100 A (INT-A-PAK Power Modules)



PRIMARY CHARACTERISTICS					
V <sub>R</sub>	1200 V				
V <sub>F</sub> (typical)	2.5 V				
t <sub>rr</sub> (typical)	150 ns				
I <sub>F(DC)</sub> at T <sub>C</sub>	110 A at 100 °C				
Package	INT-A-PAK				
Circuit configuration	Two diodes doubler circuit				

- Electrically isolated: DBC base plate
- Standard JEDEC<sup>®</sup> package
- · Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996
- Case style INT-A-PAK
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V <sub>R</sub>		1200	V		
Continuous forward current		T <sub>C</sub> = 25 °C	205			
Continuous forward current	IF	T <sub>C</sub> = 100 °C	110	А		
Single pulse forward current	I <sub>FSM</sub>	Limited by junction temperature	800			
Maximum namer discipation	Б	T <sub>C</sub> = 25 °C	695 W			
Maximum power dissipation	PD	T <sub>C</sub> = 100 °C	280	vv l		
RMS isolation voltage	VISOL	50 Hz, circuit to base, all terminal shorted, t = 1 s	3500	V		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C		

<b>ELECTRICAL SPECIFICATIONS PER LEG</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	1200	-	-		
Maximum forward voltage V <sub>FM</sub>	V	I <sub>F</sub> = 100 A	-	2.5	3.2	V	
	I <sub>F</sub> = 160 A	-	2.9	3.9			
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 150 °C, V <sub>R</sub> = 1200 V	-	18	30	mA	



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	150	200	ns
Reverse recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 160 A dI <sub>F</sub> /dt = 200 A/μs - V <sub>B</sub> = 200 V	-	20	22	А
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	2000	2400	nC
Peak rate of recovery current	dl <sub>(rec)M</sub> /dt	T <sub>J</sub> = 25 °C		-	-	300	A∕µs

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Junction operating and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C	
Maximum internal thermal r junction to case per leg	esistance,	R <sub>thJC</sub>	DC operation	0.18	°C/W	
Typical thermal resistance, case to heatsink per modul	e	R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.05		
Mounting torque + 10.%	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours	4	Nm	
Mounting torque ± 10 % -	busbar		to allow for the spread of the compound.	6		
Approximate weight				200	g	
Approximate weight	Approximate weight			7.1	oz.	
Case style				INT-A	-PAK	

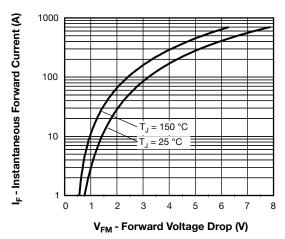


Fig. 1 - Maximum Forward Voltage Drop Characteristics

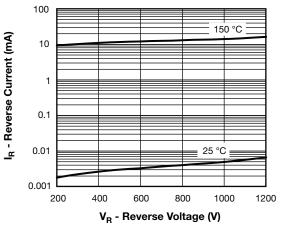


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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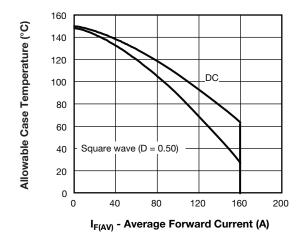


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

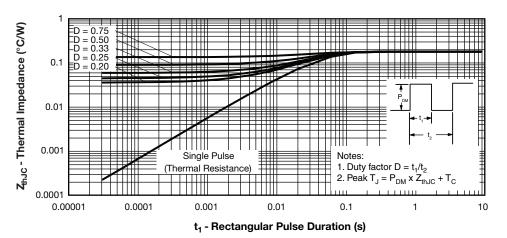


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

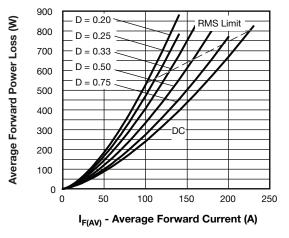


Fig. 5 - Forward Power Loss Characteristics

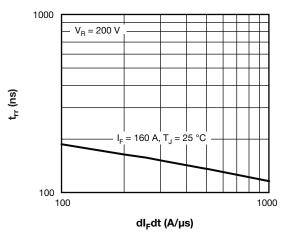


Fig. 6 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt (Per Leg)

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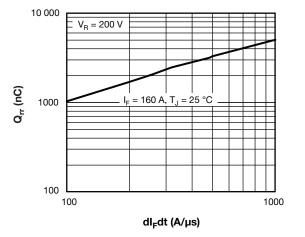


Fig. 7 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt (Per Leg)

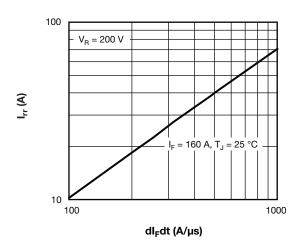
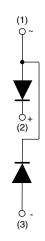


Fig. 8 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt (Per Leg)

#### **ORDERING INFORMATION TABLE**

Device code	vs-vs	KD	U	162	12	PbF
		2	3	4	5	6
	1 - 2 - 3 - 4 - 5 - 6 -	Circ U = Cur Volt	nay Sem cuit confi HEXFR rent ratii tage ratii	guratior ED <sup>®</sup> ultr ng ng (12 =	rafast di 1200 V	iode

#### **CIRCUIT CONFIGURATION**



LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95254				

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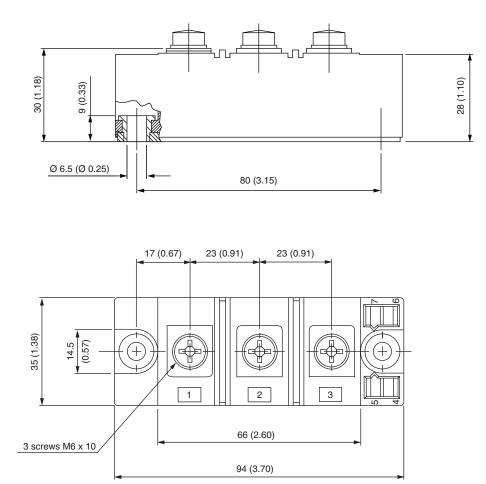


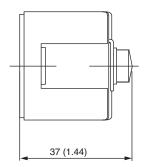
# **Outline Dimensions**

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## **INT-A-PAK DBC**

### **DIMENSIONS** in millimeters (inches)







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